74HC4051; 74HCT4051

8-channel analog multiplexer/demultiplexer Rev. 9 — 26 September 2017

Product data sheet

General description 1

The 74HC4051; 74HCT4051 is a single-pole octal-throw analog switch (SP8T) suitable for use in analog or digital 8:1 multiplexer/demultiplexer applications. The switch features three digital select inputs (S0, S1 and S2), eight independent inputs/outputs (Yn), a common input/output (Z) and a digital enable input (E). When E is HIGH, the switches are turned off. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

Features and benefits

- Wide analog input voltage range from -5 V to +5 V
- · Complies with JEDEC standard no. 7A
- · Low ON resistance:
 - 80 Ω (typical) at V_{CC} V_{EE} = 4.5 V
 - -70Ω (typical) at $V_{CC} V_{EE} = 6.0 V$
 - 60 Ω (typical) at V_{CC} V_{EE} = 9.0 V
- Logic level translation: to enable 5 V logic to communicate with ±5 V analog signals
- Typical 'break before make' built-in
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- · Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

Applications

- Analog multiplexing and demultiplexing
- · Digital multiplexing and demultiplexing
- · Signal gating

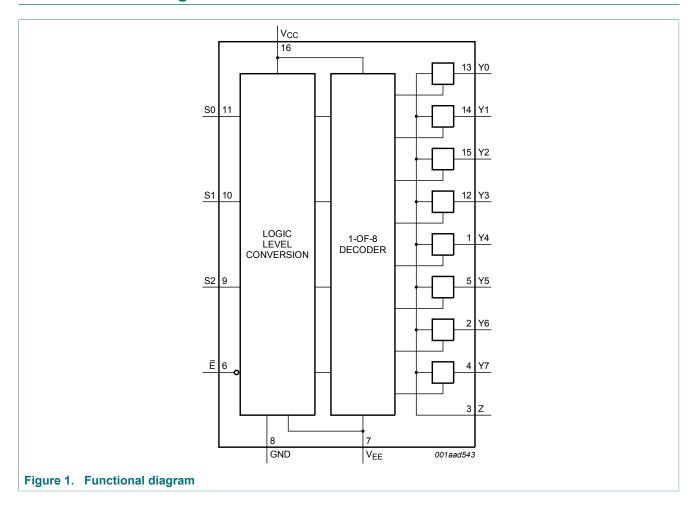


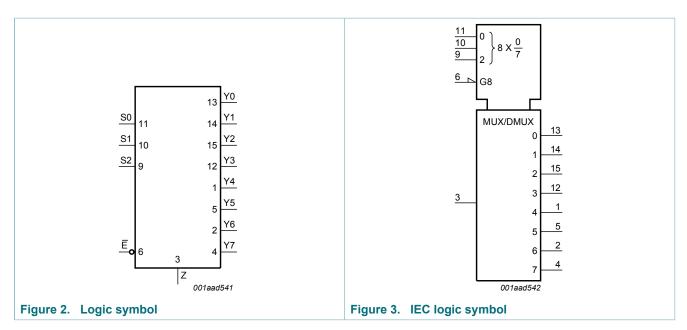
4 Ordering information

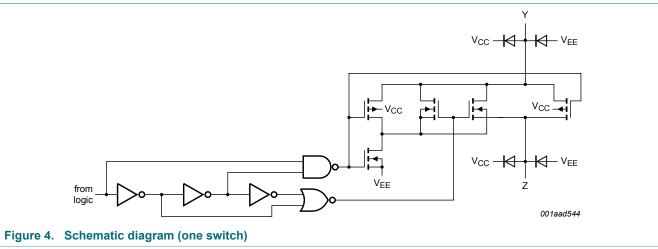
Table 1. Ordering information

Type number	Package				
	Temperature range	Name	Description	Version	
74HC4051D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1	
74HCT4051D			body width 3.9 mm		
74HC4051DB	-40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads;	SOT338-1	
74HCT4051DB			body width 5.3 mm		
74HC4051PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1	
74HCT4051PW			body width 4.4 mm		
74HC4051BQ	3Q -40 °C to +125 °C DHVQFN16		plastic dual in-line compatible thermal enhanced	SOT763-1	
74HCT4051BQ			very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm		

5 Functional diagram

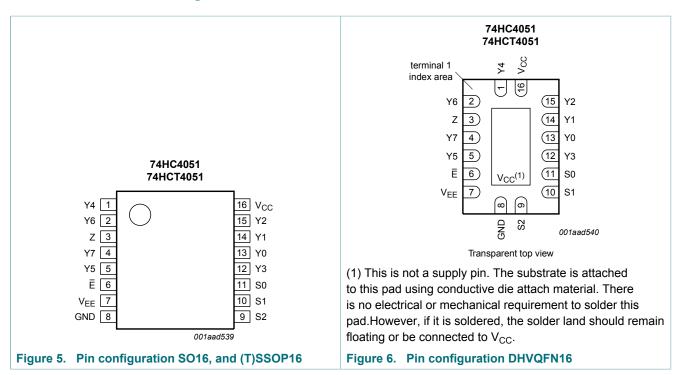






6 Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
Ē	6	enable input (active LOW)
V _{EE}	7	supply voltage
GND	8	ground supply voltage
S0, S1, S2	11, 10, 9	select input
Y0, Y1, Y2, Y3, Y4, Y5, Y6, Y7	13, 14, 15, 12, 1, 5, 2, 4	independent input or output
Z	3	common output or input
V _{CC}	16	supply voltage

7 Function description

Table 3. Function table [1]

Input				Channel ON
E	S2	S1	S0	
L	L	L	L	Y0 to Z
L	L	L	Н	Y1 to Z
L	L	Н	L	Y2 to Z
L	L	Н	Н	Y3 to Z
L	Н	L	L	Y4 to Z
L	Н	L	Н	Y5 to Z
L	Н	Н	L	Y6 to Z
L	Н	Н	Н	Y7 to Z
Н	X	X	X	switches off

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

8 Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to V_{SS} = 0 V (ground).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage	[1]	-0.5	+11.0	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{SK}	switch clamping current	V_{SW} < -0.5 V or V_{SW} > V_{CC} + 0.5 V	-	±20	mA
I _{SW}	switch current	-0.5 V < V _{SW} < V _{CC} + 0.5 V	-	±25	mA
I _{EE}	supply current		-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-	-50	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	SO16, (T)SSOP16, and DHVQFN16 package	-	500	mW
Р	power dissipation	per switch	-	100	mW

^[1] To avoid drawing V_{CC} current out of terminal Z, when switch current flows into terminals Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no V_{CC} current will flow out of terminals Yn, and in this case there is no limit for the voltage drop across the switch, but the voltages at Yn and Z may not exceed V_{CC} or V_{EE}.

74HC_HCT4051

^[2] For SO16 packages: above 70 $^{\circ}$ C the value of P_{tot} derates linearly with 8 mW/K.

For SSOP16 and TSSOP16 packages: above 60 °C the value of P_{tot} derates linearly with 5.5 mW/K.

For DHVQFN16 packages: above 60 °C the value of Ptot derates linearly with 4.5 mW/K.

9 Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions		74HC4051			74HCT4051		Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage	see <u>Figure 7</u> and <u>Figure 8</u>							
		V _{CC} - GND	2.0	5.0	10.0	4.5	5.0	5.5	V
		V _{CC} - V _{EE}	2.0	5.0	10.0	2.0	5.0	10.0	V
VI	input voltage		GND	-	V _{CC}	GND	-	V _{CC}	V
V_{SW}	switch voltage		V _{EE}	-	V _{CC}	V _{EE}	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
	rise and fall	V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
	rate	V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V
		V _{CC} = 10.0 V	-	-	31	-	-	-	ns/V

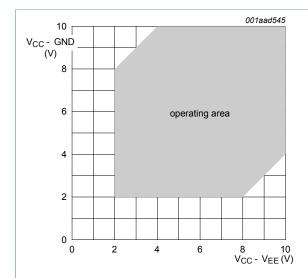


Figure 7. Guaranteed operating area as a function of the supply voltages for 74HC4051

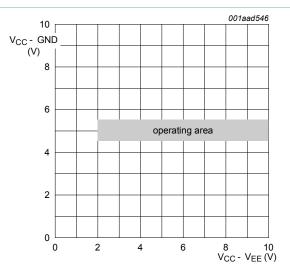


Figure 8. Guaranteed operating area as a function of the supply voltages for 74HCT4051

10 Static characteristics

Table 6. R_{ON} resistance per switch for 74HC4051 and 74HCT4051

 $V_I = V_{IH}$ or V_{IL} ; for test circuit see Figure 9.

 V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

Vos is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

For 74HC4051: V_{CC} - GND or V_{CC} - V_{EE} = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

For 74HCT4051: V_{CC} - GND = 4.5 V and 5.5 V, V_{CC} - V_{EE} = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = 25	5°C	'	,			-	
R _{ON(peak)}	ON resistance (peak)	V _{is} = V _{CC} to V _{EE}					
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	100	180	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	90	160	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μA		-	70	130	Ω
R _{ON(rail)}	ON resistance (rail)	V _{is} = V _{EE}					
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	[1]	-	150	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	80	140	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	70	120	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μA		-	60	105	Ω
		$V_{is} = V_{CC}$					
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	[1]	-	150	-	Ω
		V_{CC} = 4.5 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	90	160	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	80	140	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μA		-	65	120	Ω
ΔR_{ON}	ON resistance mismatch	$V_{is} = V_{CC}$ to V_{EE}					
	between channels	V _{CC} = 2.0 V; V _{EE} = 0 V	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	9	-	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V		-	8	-	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	6	-	Ω

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = -4	0 °C to +85 °C					-	,
R _{ON(peak)}	ON resistance (peak)	$V_{is} = V_{CC}$ to V_{EE}					
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	[1]	-	-	-	Ω
		V_{CC} = 4.5 V; V_{EE} = 0 V; I_{SW} = 1000 μ A		-	-	225	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	-	200	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μA		-	-	165	Ω
R _{ON(rail)}	ON resistance (rail)	$V_{is} = V_{EE}$					
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	[1]	-	-	-	Ω
		V_{CC} = 4.5 V; V_{EE} = 0 V; I_{SW} = 1000 μ A		-	-	175	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μ A		-	-	150	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μA		-	-	130	Ω
		V _{is} = V _{CC}					
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	[1]	-	-	-	Ω
		V_{CC} = 4.5 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	-	200	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	-	175	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μA		-	-	150	Ω
T _{amb} = -4	0 °C to +125 °C	'					
R _{ON(peak)}	ON resistance (peak)	$V_{is} = V_{CC}$ to V_{EE}					
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	[1]	-	-	-	Ω
		V_{CC} = 4.5 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	-	270	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	-	240	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μA		-	-	195	Ω
R _{ON(rail)}	ON resistance (rail)	$V_{is} = V_{EE}$					
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	[1]	-	-	-	Ω
		V_{CC} = 4.5 V; V_{EE} = 0 V; I_{SW} = 1000 μ A		-	-	210	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	-	180	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μA		-	-	160	Ω
		V _{is} = V _{CC}					
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	240	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	210	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μ A		-	-	180	Ω

^[1] When supply voltages (V_{CC} - V_{EE}) near 2.0 V the analog switch ON resistance becomes extremely non-linear. When using a supply of 2 V, it is recommended to use these devices only for transmitting digital signals.

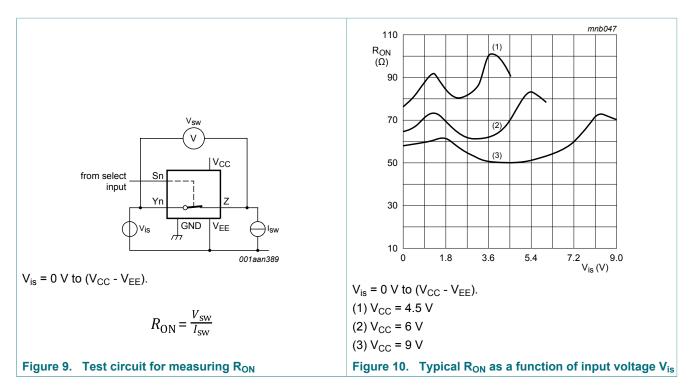


Table 7. Static characteristics for 74HC4051

Voltages are referenced to GND (ground = 0 V).

Vis is the input voltage at pins Yn or Z, whichever is assigned as an input.

Vos is the output voltage at pins Z or Yn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C			1	<u>'</u>	
V _{IH}	HIGH-level input	V _{CC} = 2.0 V	1.5	1.2	-	V
	voltage	V _{CC} = 4.5 V	3.15	2.4	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
		V _{CC} = 9.0 V	6.3	4.7	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	0.8	0.5	V
		V _{CC} = 4.5 V	-	2.1	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	V
		V _{CC} = 9.0 V	-	4.3	2.7	V
I _I	input leakage	V _{EE} = 0 V; V _I = V _{CC} or GND				
	current	V _{CC} = 6.0 V	-	-	±0.1	μΑ
		V _{CC} = 10.0 V	-	-	±0.2	μΑ
I _{S(OFF)}	OFF-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see Figure 11				
		per channel	-	-	±0.1	μΑ
		all channels	-	-	±0.4	μA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{S(ON)}	ON-state leakage current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{SW} = V_{CC} - V_{EE};$ $V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; \text{ see } Figure 12$	-	-	±0.4	μΑ
I _{CC}	supply current	V_{EE} = 0 V; V_{I} = V_{CC} or GND; V_{is} = V_{EE} or V_{CC} ; V_{os} = V_{CC} or V_{EE}				
		V _{CC} = 6.0 V	-	-	8.0	μΑ
		V _{CC} = 10.0 V	-	-	16.0	μΑ
Cı	input capacitance		-	3.5	-	pF
C _{sw}	switch	independent pins Yn	-	5	-	pF
	capacitance	common pins Z	-	25	-	pF
T _{amb} = -4	10 °C to +85 °C			1		
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
		V _{CC} = 9.0 V	6.3	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
		V _{CC} = 9.0 V	-	-	2.7	V
I _I	input leakage	V _{EE} = 0 V; V _I = V _{CC} or GND				
	current	V _{CC} = 6.0 V	-	-	±1.0	μΑ
		V _{CC} = 10.0 V	-	-	±2.0	μA
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Figure 11$				
		per channel	-	-	±1.0	μΑ
		all channels	-	-	±4.0	μΑ
I _{S(ON)}	ON-state leakage current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{SW} = V_{CC} - V_{EE};$ $V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; \text{ see Figure 12}$	-	-	±4.0	μΑ
I _{CC}	supply current	V_{EE} = 0 V; V_{I} = V_{CC} or GND; V_{is} = V_{EE} or V_{CC} ; V_{os} = V_{CC} or V_{EE}				
		V _{CC} = 6.0 V	-	-	80.0	μΑ
		V _{CC} = 10.0 V	-	-	160.0	μA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	10 °C to +125 °C			1	1	
V _{IH}	HIGH-level input	V _{CC} = 2.0 V	1.5	-	-	V
	voltage	V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
		V _{CC} = 9.0 V	6.3	-	-	V
V _{IL}	LOW-level input	V _{CC} = 2.0 V	-	-	0.5	V
	voltage	V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
		V _{CC} = 9.0 V	-	-	2.7	V
I _I	input leakage current	V _{EE} = 0 V; V _I = V _{CC} or GND				
		V _{CC} = 6.0 V	-	-	±1.0	μΑ
		V _{CC} = 10.0 V	-	-	±2.0	μΑ
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see Figure 11}$				
		per channel	-	-	±1.0	μΑ
		all channels	-	-	±4.0	μA
I _{S(ON)}	ON-state leakage current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{SW} = V_{CC} - V_{EE};$ $V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; \text{ see } Figure 12$	-	-	±4.0	μΑ
I _{CC}	supply current	V_{EE} = 0 V; V_{I} = V_{CC} or GND; V_{is} = V_{EE} or V_{CC} ; V_{os} = V_{CC} or V_{EE}				
		V _{CC} = 6.0 V	-	-	160.0	μΑ
		V _{CC} = 10.0 V	-	-	320.0	μΑ

Table 8. Static characteristics for 74HCT4051

Voltages are referenced to GND (ground = 0 V).

 V_{is} is the input voltage at pins Yn or Z, whichever is assigned as an input.

 V_{os} is the output voltage at pins Z or Yn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$; $V_{EE} = 0 \text{ V}$	-	-	±0.1	μΑ
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Figure 11$				
		per channel	-	-	±0.1	μΑ
		all channels	-	-	±0.4	μΑ
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see Figure 12}$	-	-	±0.4	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	8.0	μΑ
		V _{CC} = 5.0 V; V _{EE} = -5.0 V	-	-	16.0	μΑ
Δl _{CC}	additional supply current	per input; $V_I = V_{CC}$ - 2.1 V; other inputs at V_{CC} or GND; V_{CC} = 4.5 V to 5.5 V; V_{EE} = 0 V	-	50	180	μΑ
Cı	input capacitance		-	3.5	-	pF
C _{sw}	switch	independent pins Yn	-	5	-	pF
	capacitance	common pins Z	-	25	-	pF

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	0 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V; $V_{EE} = 0$ V	-	-	±1.0	μΑ
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Figure 11$				
		per channel	-	-	±1.0	μΑ
		all channels	-	-	±4.0	μΑ
I _{S(ON)}	ON-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see <u>Figure 12</u>	-	-	±4.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	80.0	μΑ
		V _{CC} = 5.0 V; V _{EE} = -5.0 V	-	-	160.0	μΑ
ΔI _{CC}	additional supply current	per input; $V_I = V_{CC}$ - 2.1 V; other inputs at V_{CC} or GND; V_{CC} = 4.5 V to 5.5 V; V_{EE} = 0 V	-	-	225	μΑ
T _{amb} = -4	0 °C to +125 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$; $V_{EE} = 0 \text{ V}$	-	-	±1.0	μΑ
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see Figure 11}$				
		per channel	-	-	±1.0	μΑ
		all channels	-	-	±4.0	μΑ
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see Figure 12}$	-	-	±4.0	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	160.0	μΑ
		V _{CC} = 5.0 V; V _{EE} = -5.0 V	-	-	320.0	μΑ
ΔI _{CC}	additional supply current	per input; $V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $V_{EE} = 0 \text{ V}$	-	-	245	μΑ

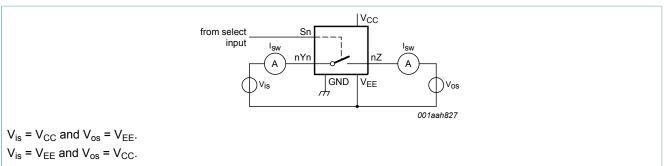
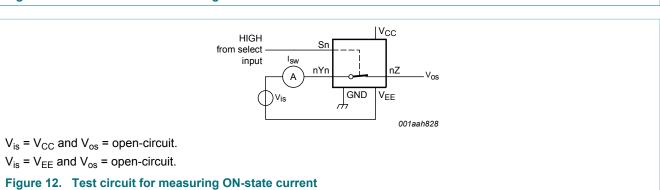


Figure 11. Test circuit for measuring OFF-state current



11 Dynamic characteristics

Table 9. Dynamic characteristics for 74HC4051

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; for test circuit see Figure 15.

 V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Figure 13</u> [1]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	14	60	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	5	12	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	4	10	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	4	8	ns
t _{on}	turn-on time	E to V_{os} ; $R_L = \infty \Omega$; see <u>Figure 14</u> [2]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	72	345	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	29	69	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	22	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	21	59	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	18	51	ns
		Sn to V_{os} ; $R_L = \infty \Omega$; see <u>Figure 14</u>				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	66	345	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	28	69	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	20	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	19	59	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	16	51	ns
t _{off}	turn-off time	E to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	58	290	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	31	58	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	18	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	17	49	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	18	42	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	61	290	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	25	58	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	19	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	18	49	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	18	42	ns

74HC HCT4051

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{PD}	power dissipation	per switch; $V_I = GND$ to V_{CC} [4]	-	25	-	pF
	capacitance					
$T_{amb} = -4$	0 °C to +85 °C					
t_{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Figure 13</u> [1]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	75	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	15	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	13	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	10	ns
t _{on}	turn-on time	E to V_{os} ; $R_L = \infty \Omega$; see <u>Figure 14</u> [2]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	430	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	86	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	73	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	64	ns
		Sn to V_{os} ; $R_L = \infty \Omega$; see <u>Figure 14</u> [2]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	430	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	86	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	73	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	64	ns
t _{off}	turn-off time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see <u>Figure 14</u> [3]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	365	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	73	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	62	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	53	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see <u>Figure 14</u>				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	365	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	_	73	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	62	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	53	ns

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	0 °C to +125 °C					
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Figure 13</u> [1]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	90	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	18	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	15	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	12	ns
t _{on}	turn-on time	\overline{E} to $V_{os}; R_{L} = \infty \Omega;$ see <u>Figure 14</u>				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	520	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	104	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	88	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	77	ns
		Sn to V_{os} ; $R_L = \infty \Omega$; see <u>Figure 14</u>				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	520	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	104	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	88	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	77	ns
t _{off}	turn-off time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see Figure 14				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	435	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	87	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	74	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	72	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	435	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	87	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	74	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	72	ns

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$ where: f_i = input frequency in MHz;

f_o = output frequency in MHz;

N = number of inputs switching; $\Sigma\{(C_L + C_{sw}) \times V_{CC}^2 \times f_0\} = \text{sum of outputs};$ $C_L = \text{output load capacitance in pF};$

C_{sw} = switch capacitance in pF;

 V_{CC} = supply voltage in V.

 ^[1] t_{pd} is the same as t_{PHL} and t_{PLH}.
 [2] t_{on} is the same as t_{PZH and} t_{PZL}.
 [3] t_{off} is the same as t_{PHZ} and t_{PLZ}.
 [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

Table 10. Dynamic characteristics for 74HCT4051

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; for test circuit see Figure 15.

 V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	5 °C					
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Figure 13</u> [1]				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	5	12	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	4	8	ns
t _{on}	turn-on time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see <u>Figure 14</u>				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	26	55	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	22	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	16	39	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	28	55	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	24	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	16	39	ns
t _{off}	turn-off time	E to V_{os} ; $R_L = 1 \text{ k}\Omega$; see <u>Figure 14</u>				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	19	45	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	16	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	16	32	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see <u>Figure 14</u> [3]				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	23	45	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	20	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	16	32	ns
C _{PD}	power dissipation capacitance	per switch; $V_I = GND$ to $V_{CC} - 1.5 V$ [4]	-	25	-	pF
T _{amb} = -4	0 °C to +85 °C					
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see Figure 13				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	15	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	10	ns
t _{on}	turn-on time	$\overline{\mathbb{E}}$ to V _{os} ; R _L = 1 k Ω ; see <u>Figure 14</u>				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	69	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	49	ns
		Sn to V_{os} ; $R_L = 1 k\Omega$; see <u>Figure 14</u> [2]				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	69	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	49	ns

74HC_HCT4051

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{off}	turn-off time	E to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	56	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	40	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	56	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	40	ns
Γ _{amb} = -4	0 °C to +125 °C					
pd	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Figure 13</u> [1]				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	18	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	12	ns
on	turn-on time	E to V_{os} ; $R_L = 1 kΩ$; see Figure 14				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	83	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	59	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	83	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	59	ns
off	turn-off time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see <u>Figure 14</u>				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	68	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	48	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	68	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	48	ns

^[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

 $P_D = C_{PD} x V_{CC}^2 x f_i x N + \Sigma \{(C_L + C_{sw}) x V_{CC}^2 x f_o\}$ where:

 f_i = input frequency in MHz;

fo = output frequency in MHz;

N = number of inputs switching;

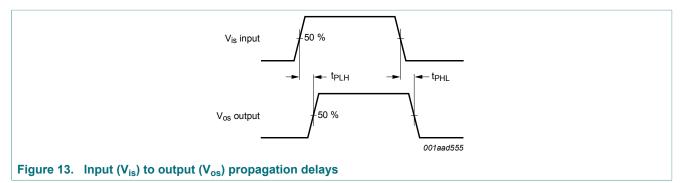
 $\Sigma\{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\} = \text{sum of outputs};$

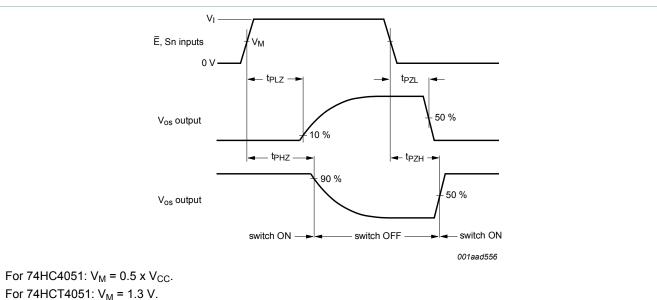
C_L = output load capacitance in pF;

C_{sw} = switch capacitance in pF;

 V_{CC} = supply voltage in V.

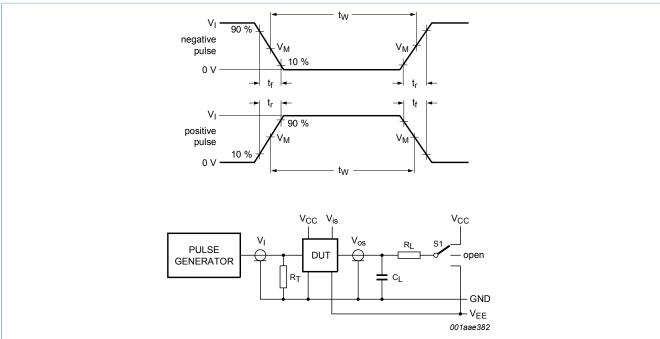
 ^[3] t_{on} is the same as t_{PHZ} and t_{PLZ}.
 [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).





For 74HCT4051: $V_M = 1.3 V$.

Figure 14. Turn-on and turn-off times



Definitions for test circuit; see Table 11:

 R_T = termination resistance should be equal to the output impedance Z_0 of the pulse generator.

 $\ensuremath{\text{C}_{\text{L}}}$ = load capacitance including jig and probe capacitance.

R_I = load resistance.

S1 = Test selection switch.

Figure 15. Test circuit for measuring switching times

Table 11. Test data

Test	Input				Load		S1 position	
	V _I	V _{is}	t _r , t _f		CL	R _L		
			at f _{max}	other [1]				
t _{PHL} , t _{PLH}	[2]	pulse	< 2 ns	6 ns	50 pF	1 kΩ	open	
t _{PZH} , t _{PHZ}	[2]	V _{CC}	< 2 ns	6 ns	50 pF	1 kΩ	V _{EE}	
t _{PZL} , t _{PLZ}	[2]	V _{EE}	< 2 ns	6 ns	50 pF	1 kΩ	V _{CC}	

^[1] $t_r = t_f = 6$ ns; when measuring f_{max} , there is no constraint to t_r and t_f with 50 % duty factor.

[2] V_I values:

For 74HC4051: $V_I = V_{CC}$ For 74HCT4051: $V_I = 3 \text{ V}$

11.1 Additional dynamic characteristics

Table 12. Additional dynamic characteristics

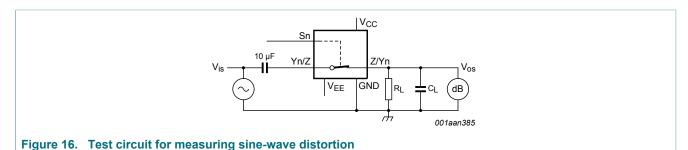
Recommended conditions and typical values; GND = 0 V; T_{amb} = 25 °C; C_L = 50 pF.

 V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

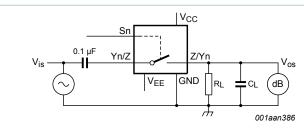
V_{os} is the output voltage at pins nYn or nZ, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
d _{sin}	sine-wave distortion	f_i = 1 kHz; R_L = 10 k Ω ; see <u>Figure 16</u>				
		V_{is} = 4.0 V (p-p); V_{CC} = 2.25 V; V_{EE} = -2.25 V	-	0.04	-	%
		V_{is} = 8.0 V (p-p); V_{CC} = 4.5 V; V_{EE} = -4.5 V	-	0.02	-	%
		f_i = 10 kHz; R_L = 10 kΩ; see Figure 16				
		V_{is} = 4.0 V (p-p); V_{CC} = 2.25 V; V_{EE} = -2.25 V	-	0.12	-	%
		V_{is} = 8.0 V (p-p); V_{CC} = 4.5 V; V_{EE} = -4.5 V	-	0.06	-	%
α_{iso}	isolation (OFF-state)	$R_L = 600 \Omega$; $f_i = 1 MHz$; see Figure 17				
		$V_{CC} = 2.25 \text{ V}; V_{EE} = -2.25 \text{ V}$ [1]	-	-50	-	dB
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$ [1]	-	-50	-	dB
V _{ct}	crosstalk voltage	peak-to-peak value; between control and any switch; R_L = 600 Ω ; f_i = 1 MHz; E or Sn square wave between V_{CC} and GND; t_r = t_f = 6 ns; see Figure 18				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	110	-	mV
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	220	-	mV
f _(-3dB)	-3 dB frequency response	R_L = 50 Ω; see <u>Figure 19</u>				
		$V_{CC} = 2.25 \text{ V}; V_{EE} = -2.25 \text{ V}$ [2]	-	170	-	MHz
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$ [2]	-	180	-	MHz

- [1] Adjust input voltage V_{is} to 0 dBm level (0 dBm = 1 mW into 600 Ω).
- [2] Adjust input voltage V_{is} to 0 dBm level at V_{os} for 1 MHz (0 dBm = 1 mW into 50 Ω).

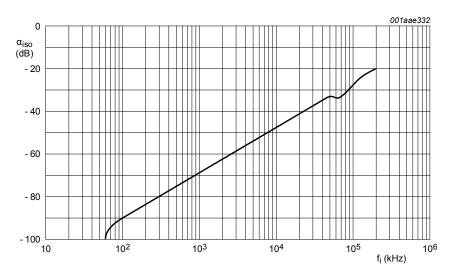


74HC_HCT4051



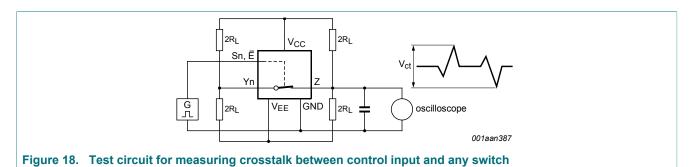
 V_{CC} = 4.5 V; GND = 0 V; V_{EE} = -4.5 V; R_L = 600 Ω ; R_S = 1 k Ω .

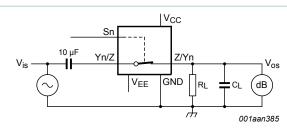
a. Test circuit



b. Isolation (OFF-state) as a function of frequency

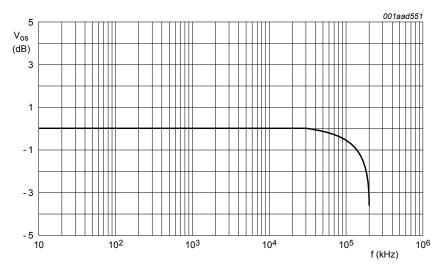
Figure 17. Test circuit for measuring isolation (OFF-state)





 V_{CC} = 4.5 V; GND = 0 V; V_{EE} = -4.5 V; R_L = 50 Ω ; R_S = 1 k Ω .

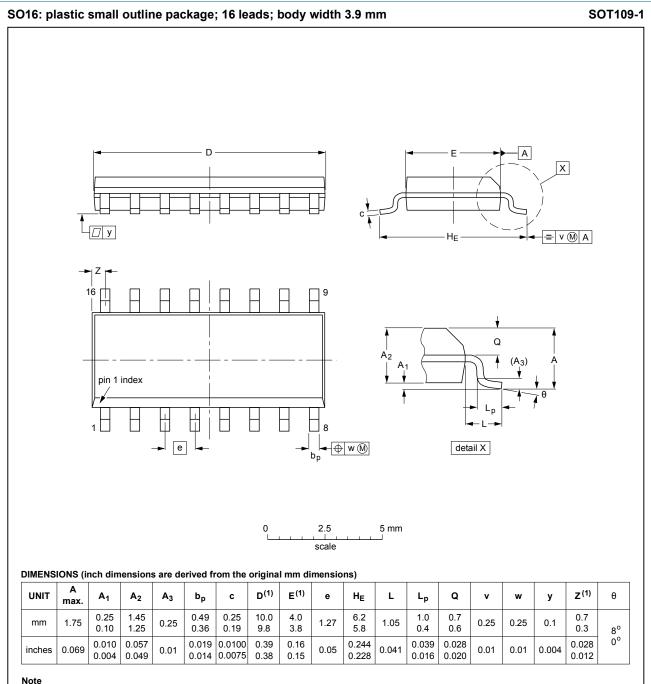
a. Test circuit



b. Typical frequency response

Figure 19. Test circuit for frequency response

12 Package outline



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

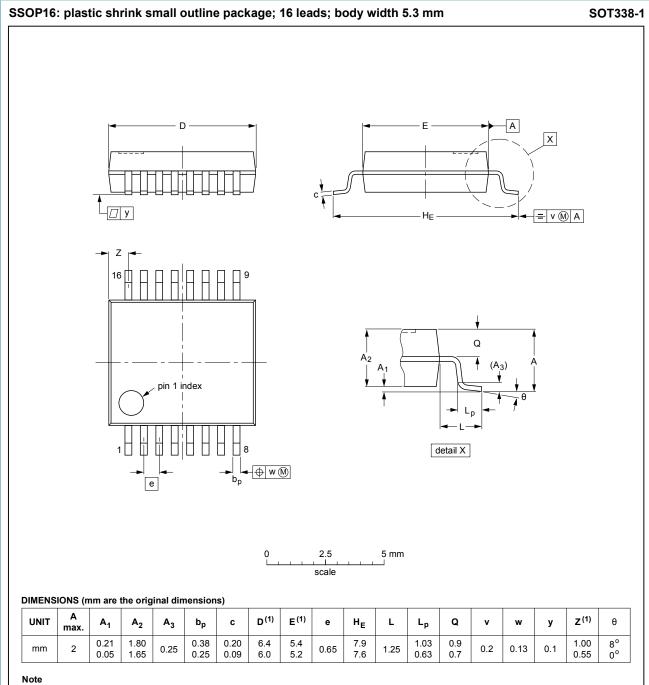
OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012			99-12-27 03-02-19	

Figure 20. Package outline SOT109-1 (SO16)

74HC_HCT4051

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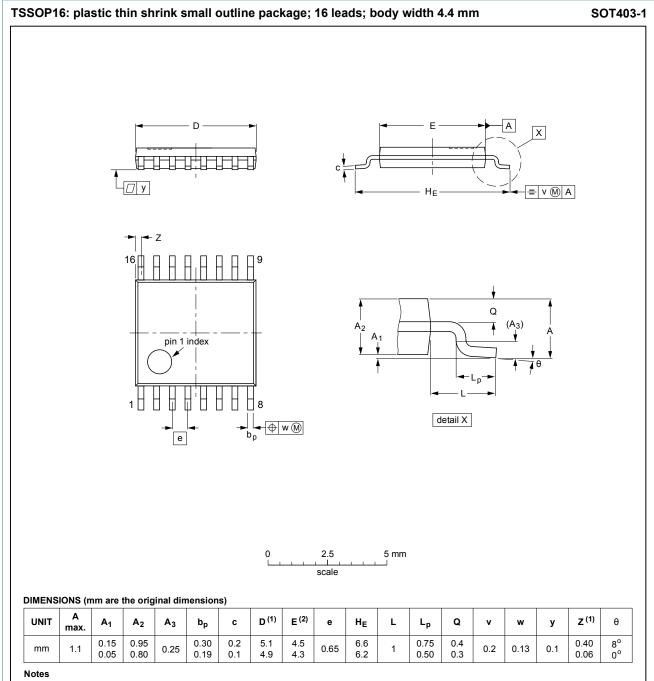
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1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT338-1		MO-150			99-12-27 03-02-19	

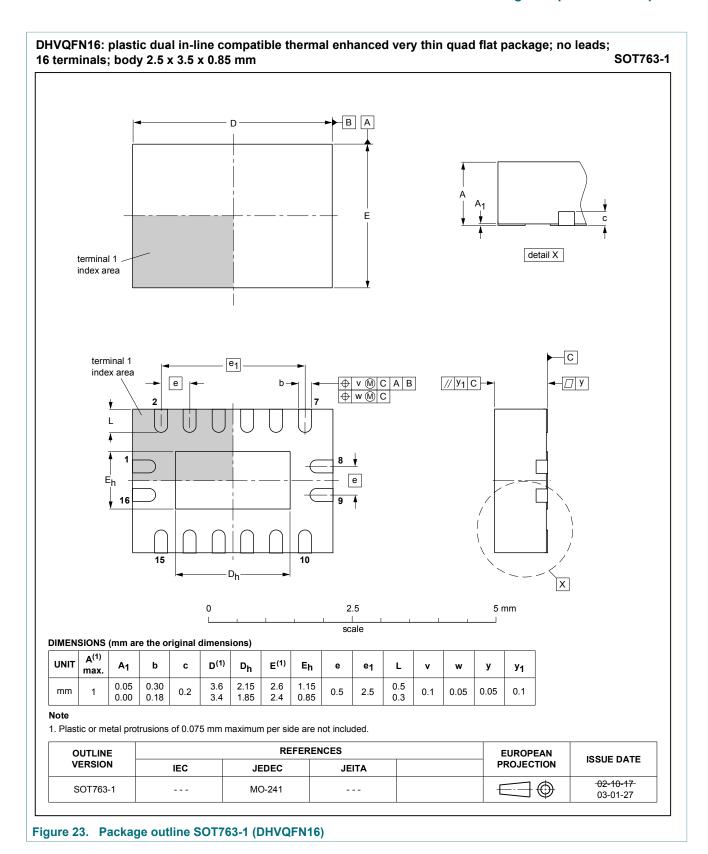
Figure 21. Package outline SOT338-1 (SSOP16)



- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT403-1		MO-153			99-12-27 03-02-18	

Figure 22. Package outline SOT403-1 (TSSOP16)



74HC_HCT4051

13 Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

14 Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74HC_HCT4051 v.9	20170926	Product data sheet	-	74HC_HCT4051 v.8			
Modifications:	Nexperia.	The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate.					
74HC_HCT4051 v.8	20160205	Product data sheet	-	74HC_HCT4051 v.7			
Modifications:	Type numbers 7	74HC4051N and 74HCT40	51N (SOT38-4) rem	oved.			
74HC_HCT4051 v.7	20120719	Product data sheet	-	74HC_HCT4051 v.6			
Modifications:	 CDM added to f 	eatures.					
74HC_HCT4051 v.6	20111213	Product data sheet	-	74HC_HCT4051 v.5			
Modifications:	Legal pages upo	dated.					
74HC_HCT4051 v.5	20110513	Product data sheet	-	74HC_HCT4051 v.4			
74HC_HCT4051 v.4	20110117	Product data sheet	-	74HC_HCT4051 v.3			
74HC_HCT4051 v.3	20051219	Product specification	-	74HC_HCT4051_CNV_2			

15 Legal information

15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- The term 'short data sheet' is explained in section "Definitions". [2] [3]
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74HC4051; 74HCT4051

8-channel analog multiplexer/demultiplexer

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